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Stocking Distributor

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[IXYS Corporation](#)
[VUO35-12NO7](#)

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sales@integrated-circuit.com

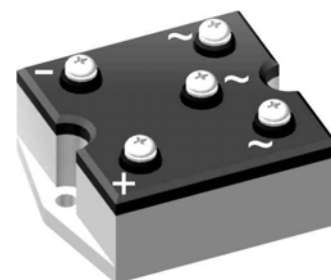
Standard Rectifier Module

| | |
|-------------------------|----------|
| 3~ Rectifier | |
| V_{RRM} | = 1200 V |
| I_{DAV} | = 35 A |
| I_{FSM} | = 400 A |

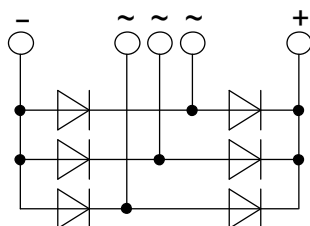
3~ Rectifier Bridge

Part number

VUO35-12N07



 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: PWS-A

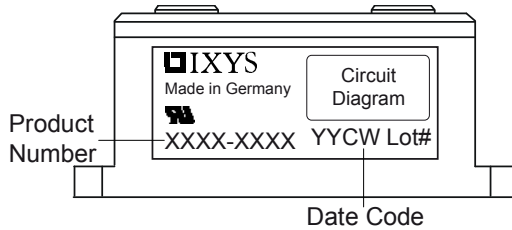
- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Aluminium internally DCB isolated
- Advanced power cycling

| Rectifier | | | | Ratings | | | |
|------------|--|---|------------------------------|------------------------------|------|------------------|------------------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | 1300 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | 1200 | V | |
| I_R | reverse current | $V_R = 1200\text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ | | 40 | μA | |
| | | $V_R = 1200\text{ V}$ | $T_{VJ} = 150^\circ\text{C}$ | | 1.5 | mA | |
| V_F | forward voltage drop | $I_F = 15\text{ A}$ | $T_{VJ} = 25^\circ\text{C}$ | | 1.10 | V | |
| | | | | | 1.38 | V | |
| | | $I_F = 45\text{ A}$ | $T_{VJ} = 125^\circ\text{C}$ | | 1.01 | V | |
| | | | | | 1.38 | V | |
| I_{DAV} | bridge output current | $T_C = 85^\circ\text{C}$ rectangular $d = 1/3$ | $T_{VJ} = 150^\circ\text{C}$ | | 35 | A | |
| | | | | | | | |
| V_{F0} | threshold voltage | } for power loss calculation only | $T_{VJ} = 150^\circ\text{C}$ | | 0.80 | V | |
| r_F | slope resistance | | | | 12.9 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 4.2 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.6 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^\circ\text{C}$ | | 29 | W | |
| I_{FSM} | max. forward surge current | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 45^\circ\text{C}$ | | 400 | A | |
| | | | | | 430 | A | |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | $T_{VJ} = 150^\circ\text{C}$ | | 340 | A |
| | | | | | | 365 | A |
| I^2t | value for fusing | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 45^\circ\text{C}$ | | 800 | A ² s | |
| | | | | | 770 | A ² s | |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | $T_{VJ} = 150^\circ\text{C}$ | | 580 | A ² s |
| | | | | | | 555 | A ² s |
| C_J | junction capacitance | $V_R = 400\text{ V}; f = 1\text{ MHz}$ | $T_{VJ} = 25^\circ\text{C}$ | 10 | | pF | |



VUO35-12NO7

| Package PWS-A | | Ratings | | | | |
|---------------|--|----------------------|------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 100 | A |
| T_{stg} | storage temperature | | -40 | | 125 | °C |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| Weight | | | | 100 | | g |
| M_D | mounting torque | | 1.25 | | 1.75 | Nm |
| M_T | terminal torque | | 1.25 | | 1.75 | Nm |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 6.5 | | | mm |
| $d_{Spb/App}$ | | terminal to backside | 8.5 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second | 3000 | | | V |
| | | t = 1 minute | 2500 | | | V |

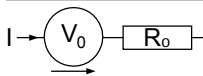


| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | VUO35-12NO7 | VUO35-12NO7 | Box | 20 | 456632 |

Equivalent Circuits for Simulation

* on die level

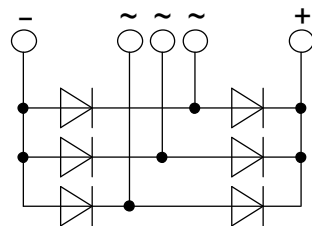
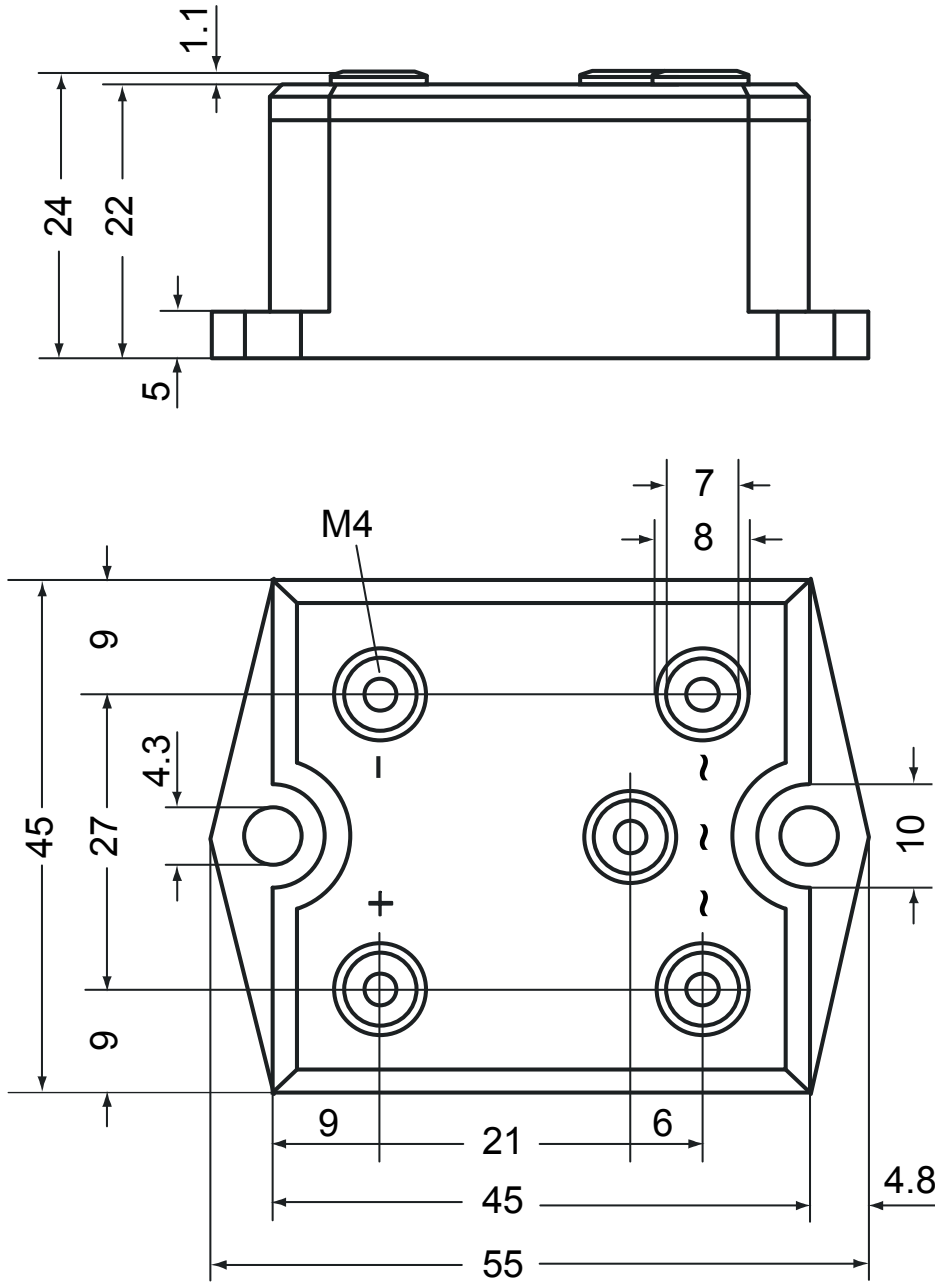
$T_{VJ} = 150\text{ °C}$



Rectifier

| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0.8 | V |
| $R_{0\ max}$ | slope resistance * | 11.7 | mΩ |

Outlines PWS-A



Rectifier

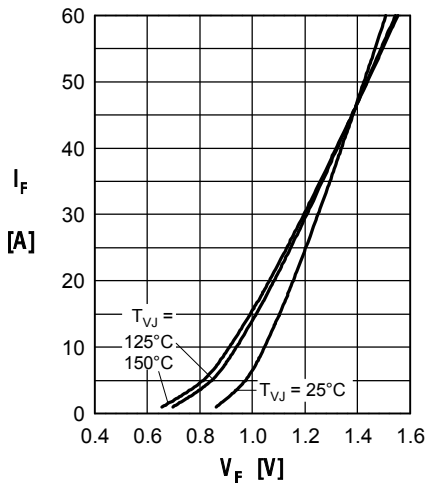


Fig. 1 Forward current vs. voltage drop per diode

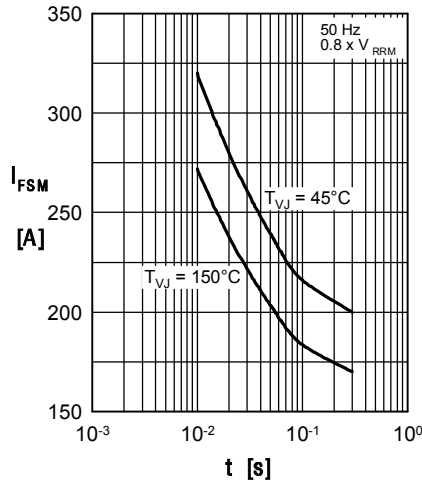


Fig. 2 Surge overload current vs. time per diode

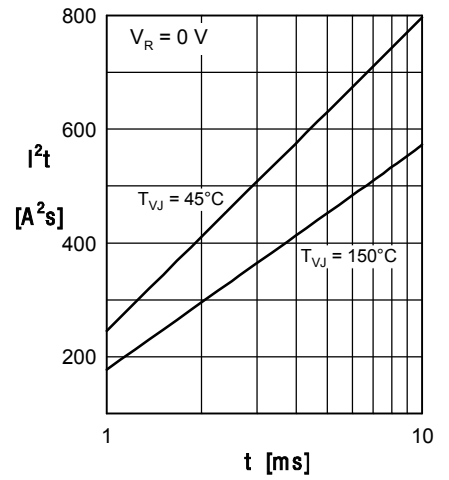


Fig. 3 I²t vs. time per diode

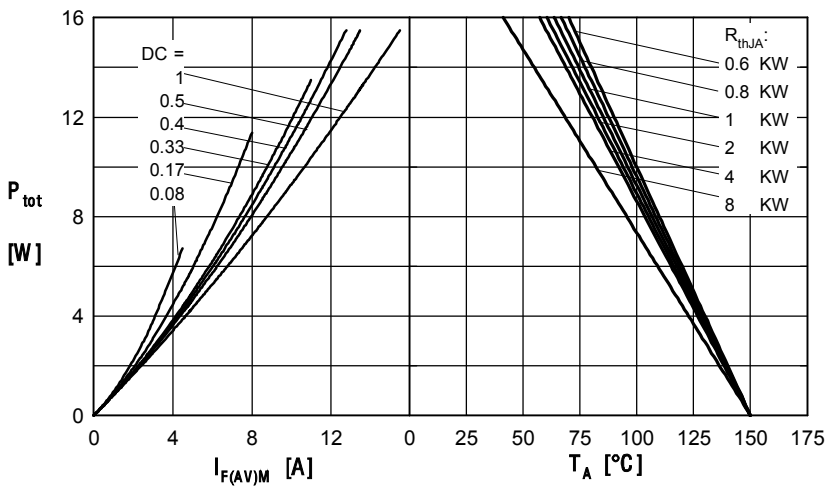


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

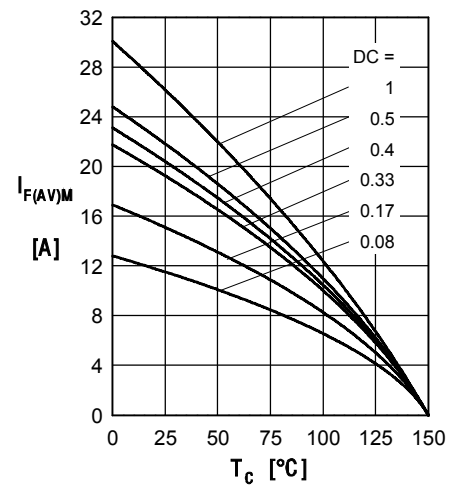


Fig. 5 Max. forward current vs. case temperature per diode

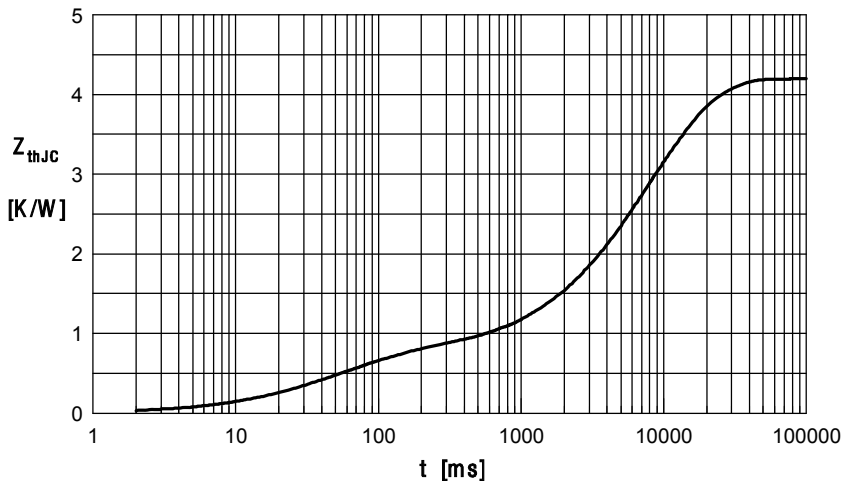


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

| i | R _{th} (K/W) | t _i (s) |
|---|-----------------------|--------------------|
| 1 | 0.194 | 0.024 |
| 2 | 0.556 | 0.070 |
| 3 | 0.450 | 3.250 |
| 4 | 3.000 | 9.300 |